

600W LLC Demo Board

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IFAT PMM APS SE AC
HV DC/DC Converters Applications



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Prototype Specifications

Half Bridge LLC with synchronous rectification in center tap configuration

V_{in}	350-410V _{DC}
V_{in_nom}	380V _{DC}
V_{out_nom}	12V _{DC}
I_{out}	50A
P_o	600W
$f_{res}=f_0$	157kHz
f_{min}	90kHz
f_{max}	210kHz
Transformer turns ratio	16:1
C_r	66nF
L_r	15.5uH
L_m	195uH

Primary HV MOSFETs

- CoolMOS™ IPP60R190P6
- Reduced Gate Charge (Q_g)
- Reduced E_{off}
- High body diode ruggedness

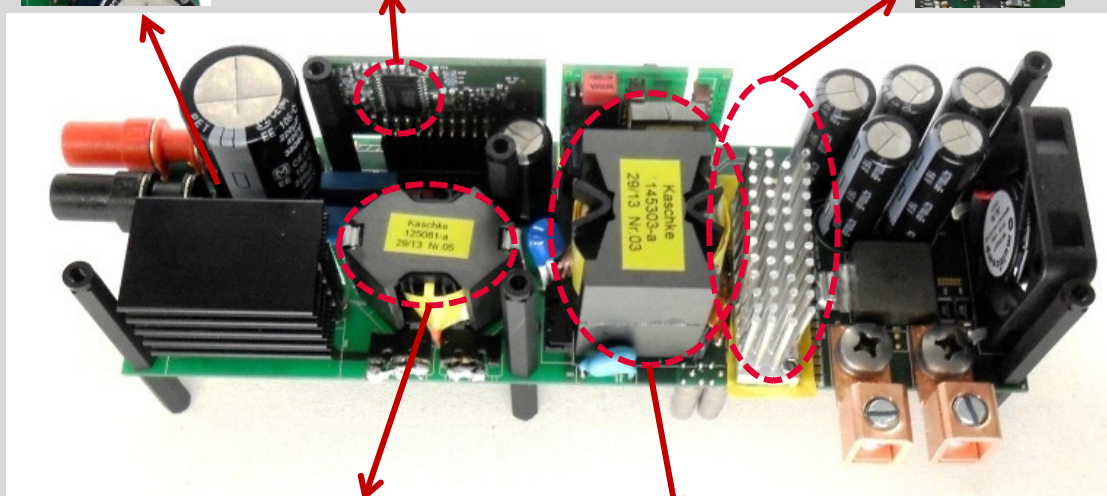
SR MOSFETs

- OptiMOS™ BSC010N04LS
- New generation
- Best FOM $R_{ds,on} \times Q_g$
- Best FOM $R_{ds,on} \times Q_{oss}$



LLC analog controller
ICE2HS01G
HB Gate Drive IC
2EDL05N06PF

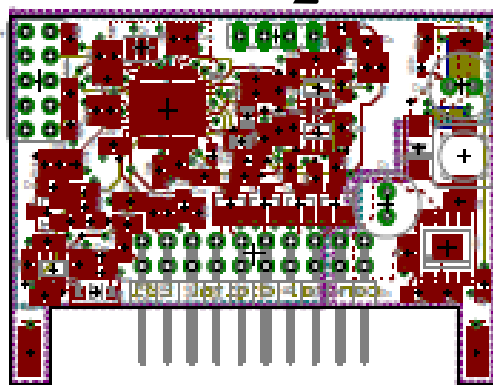
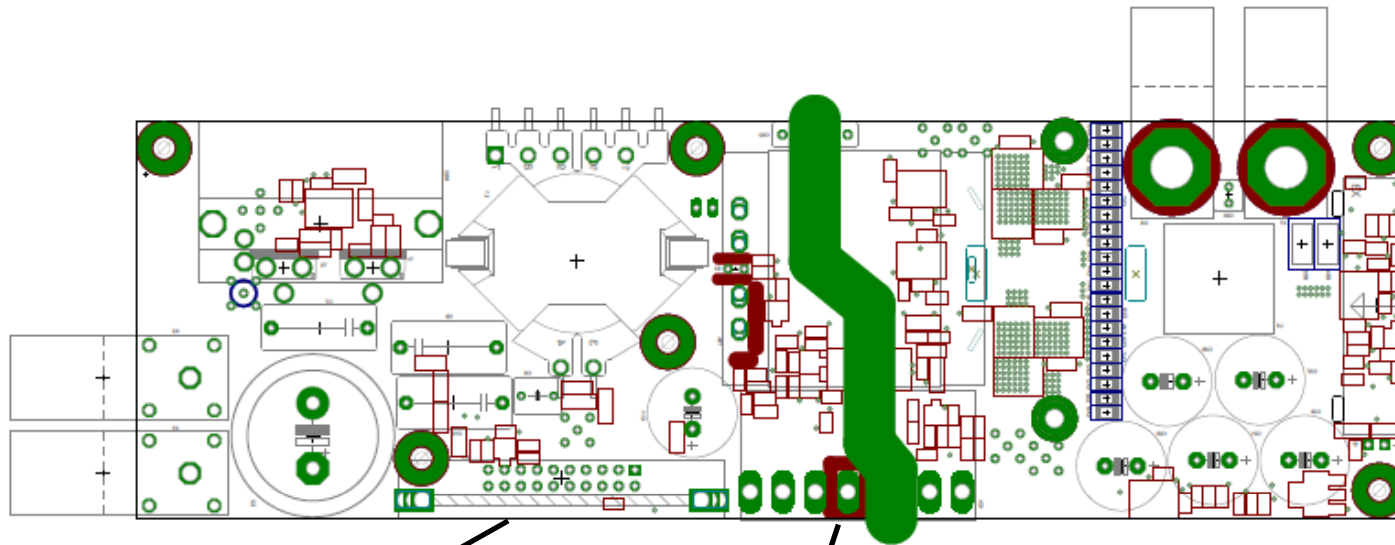
Bias QR Flyback
controller
ICE2QR2280Z



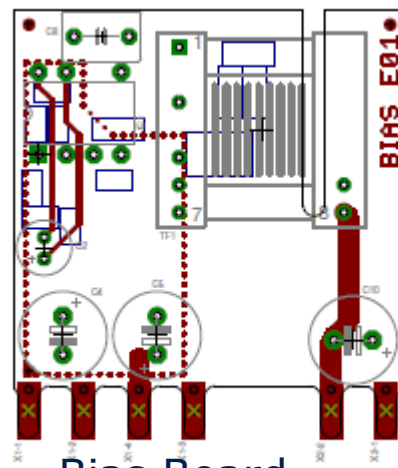
Resonant inductor
RM12 core

Transformer
PQ35/35 core

PCB Boards Layout: main power board and Control and Bias daughter boards



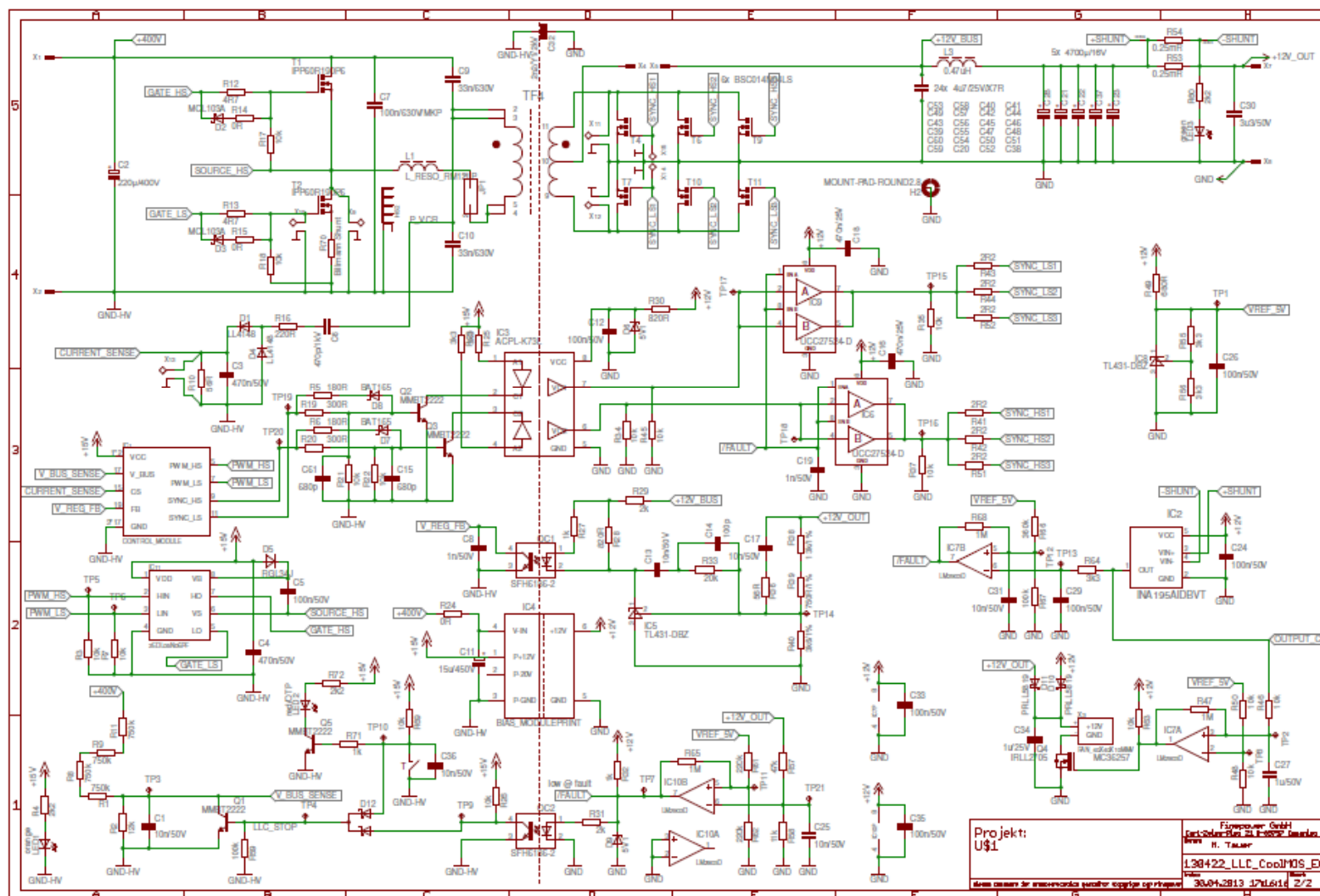
Controller Board



Bias Board

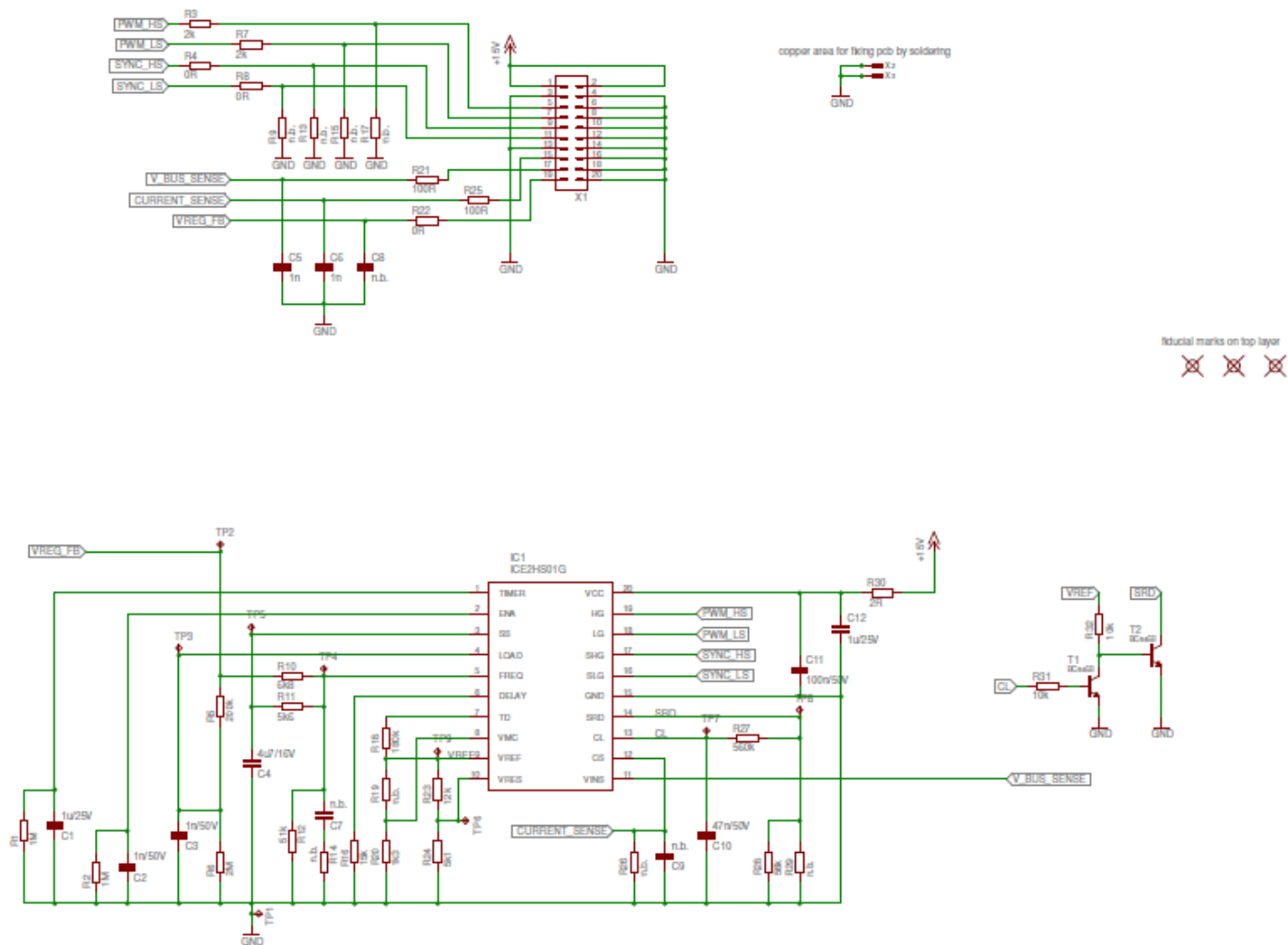
- Power Density > 20W/inch³

Main Power Board Schematic



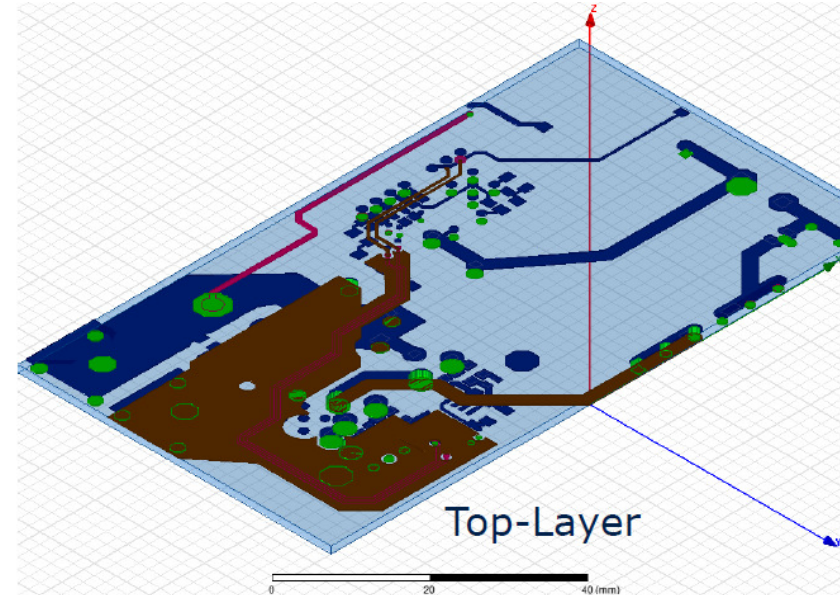
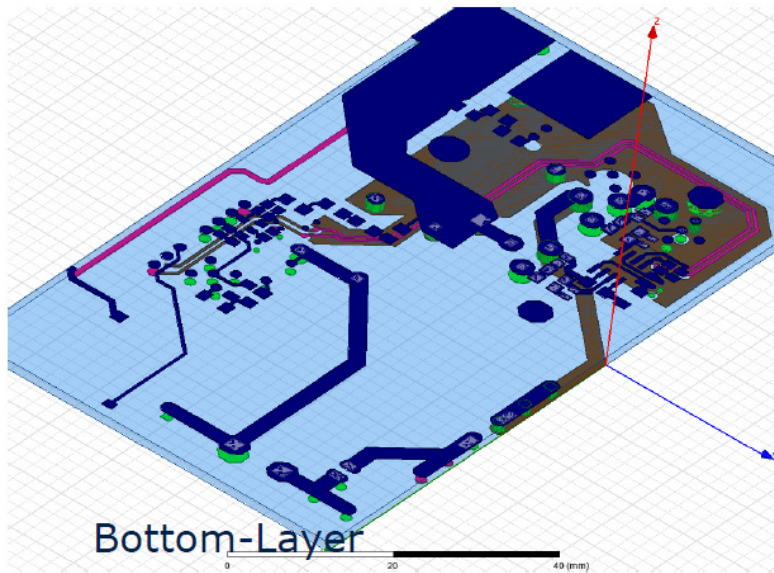


Analog Control Board Schematic





PCB structure



PCB-Stackup

Nr	Copper		Isolation	
1	0.07mm		0.15mm	
2	0.07mm		0.93mm	
15	0.07mm		0.15mm	
16	0.07mm			
Gesamt: 1.51mm				

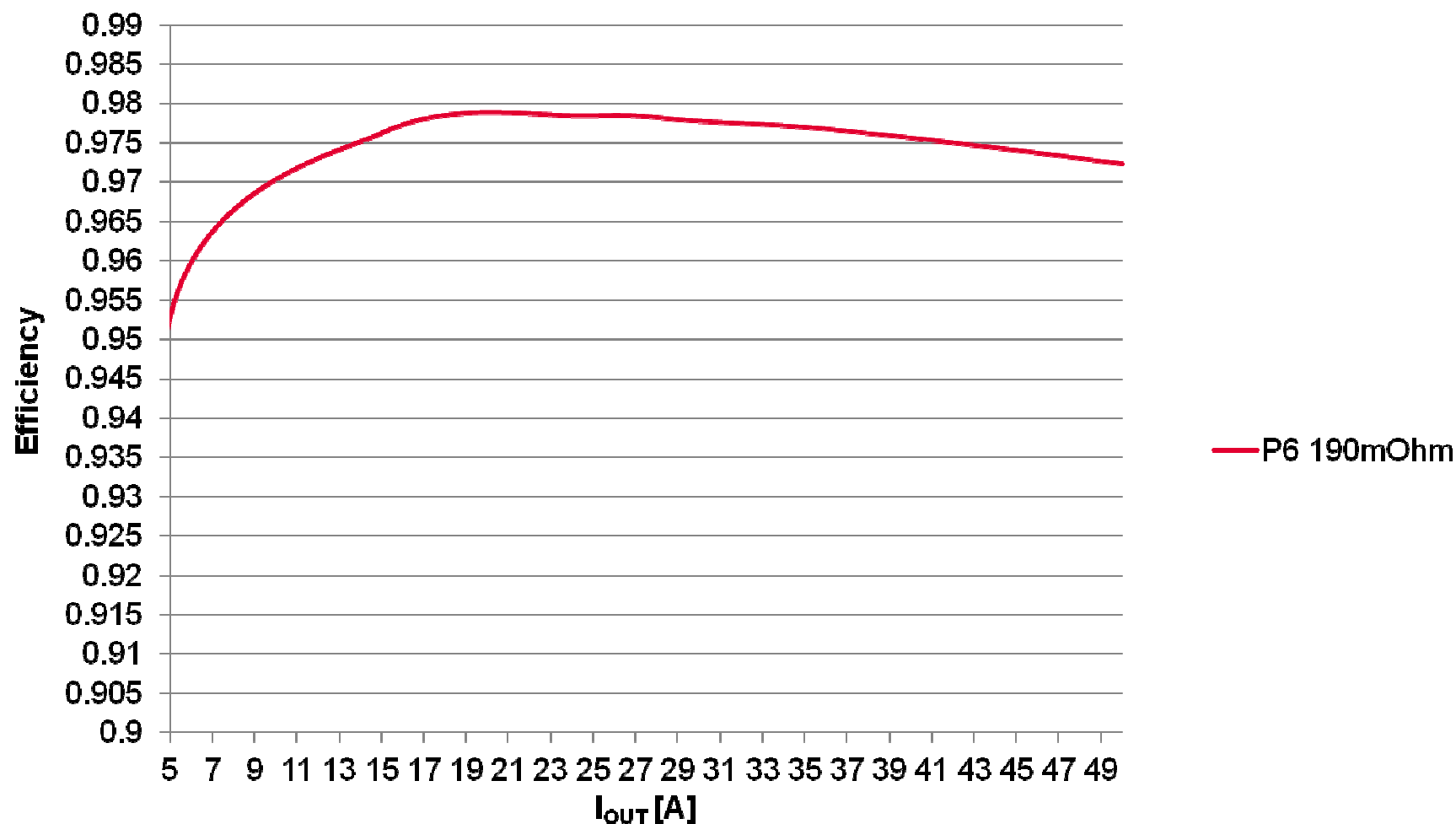
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■ General description

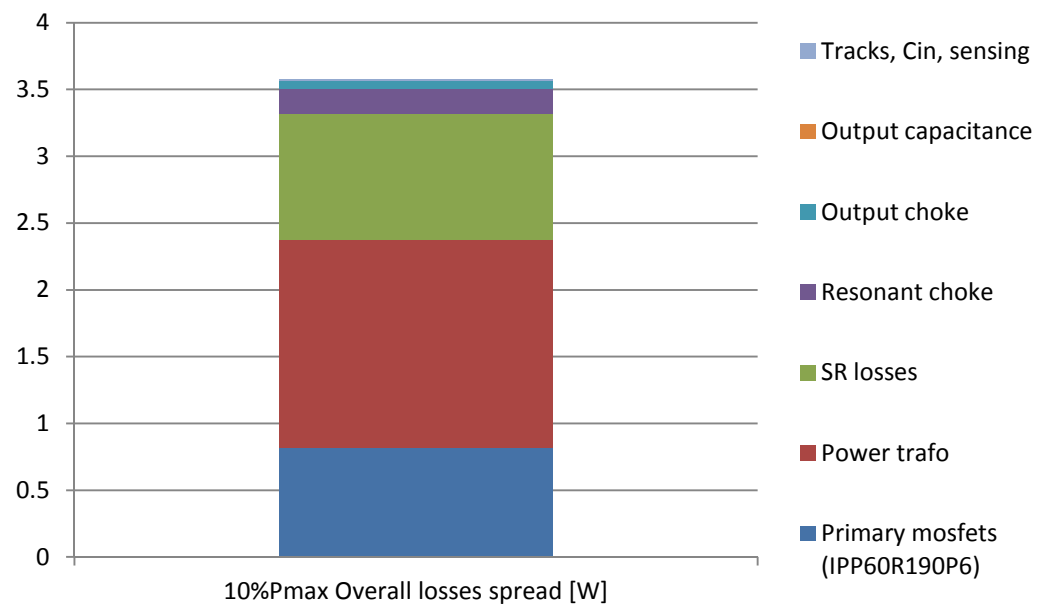
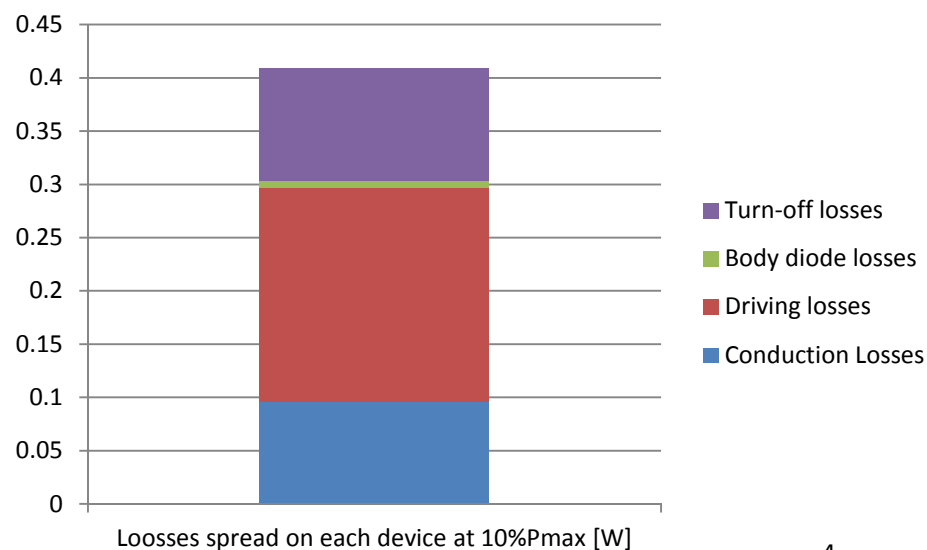
■ **Efficiency results**

■ Design Concept

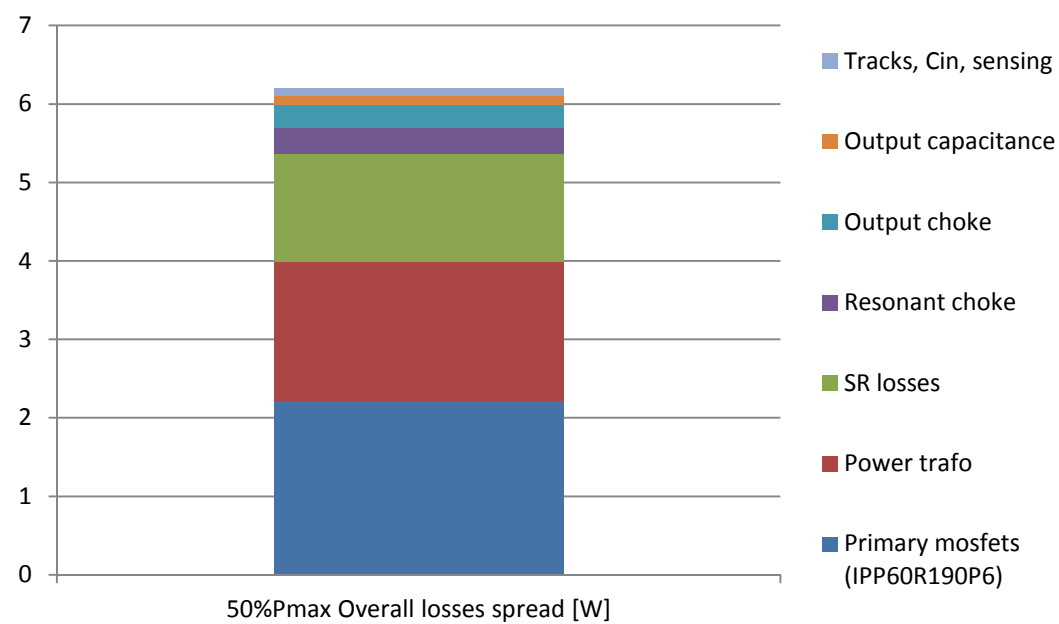
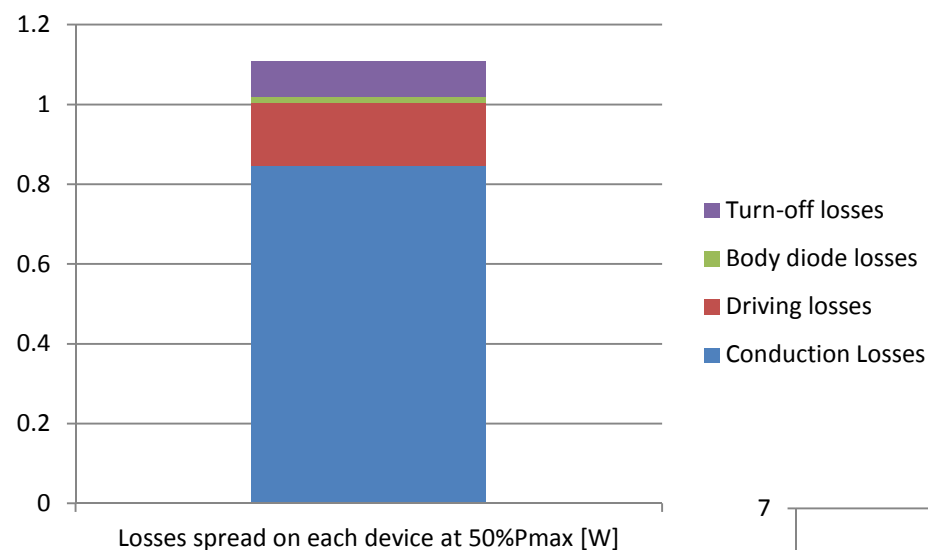
Efficiency plot at $V_{in}=380V_{dc}$ (Bias consumption not included)



10%Pmax Vin=380Vdc



50%Pmax Vin=380Vdc



100%Pmax Vin=380Vdc

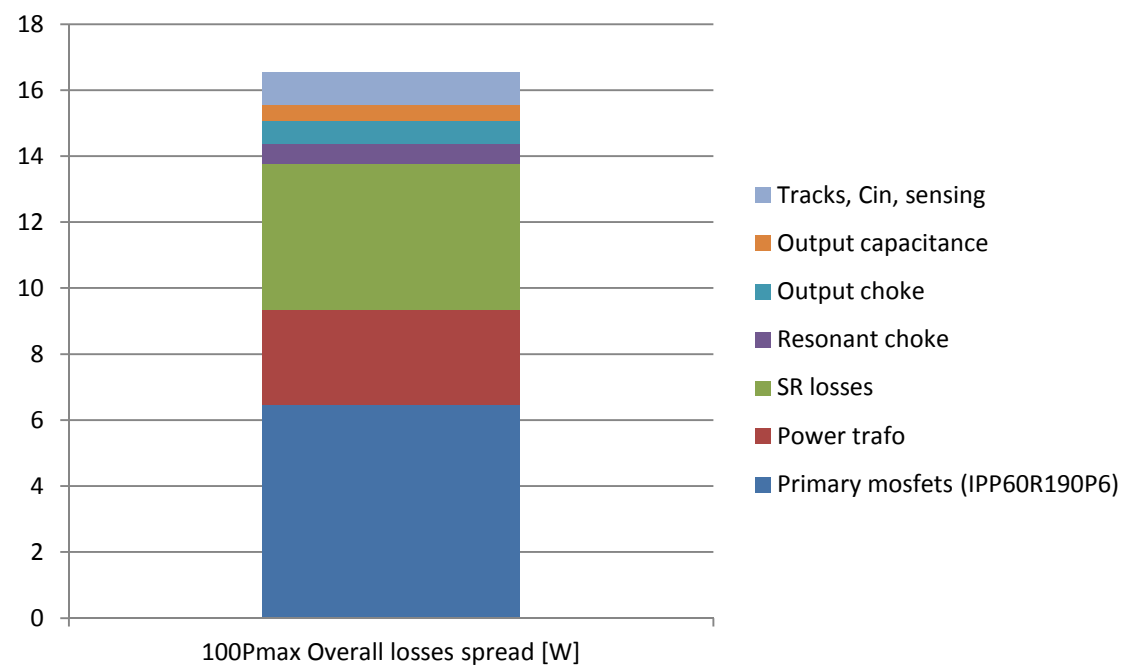
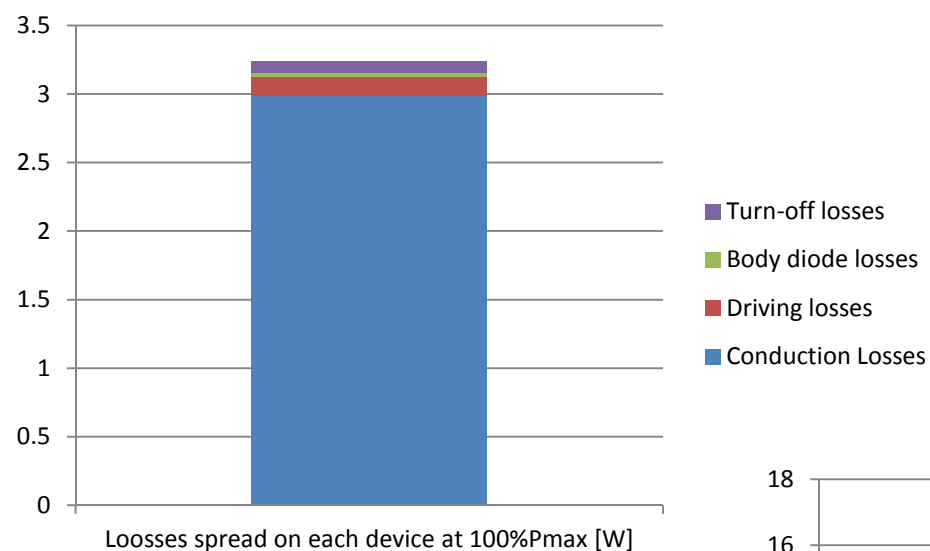


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Design procedure: input data

$$n = \frac{V_{in_nom}}{2 \cdot V_{out_nom}}$$

$$M_{min} \equiv K_{min}(Q, m, F_x) = \frac{n \cdot V_{o_min}}{V_{in_max} / 2}$$

$$M_{max} \equiv K_{max}(Q, m, F_x) = \frac{n \cdot V_{o_max}}{V_{in_min} / 2}$$

Resonant tank components and related resonant frequencies

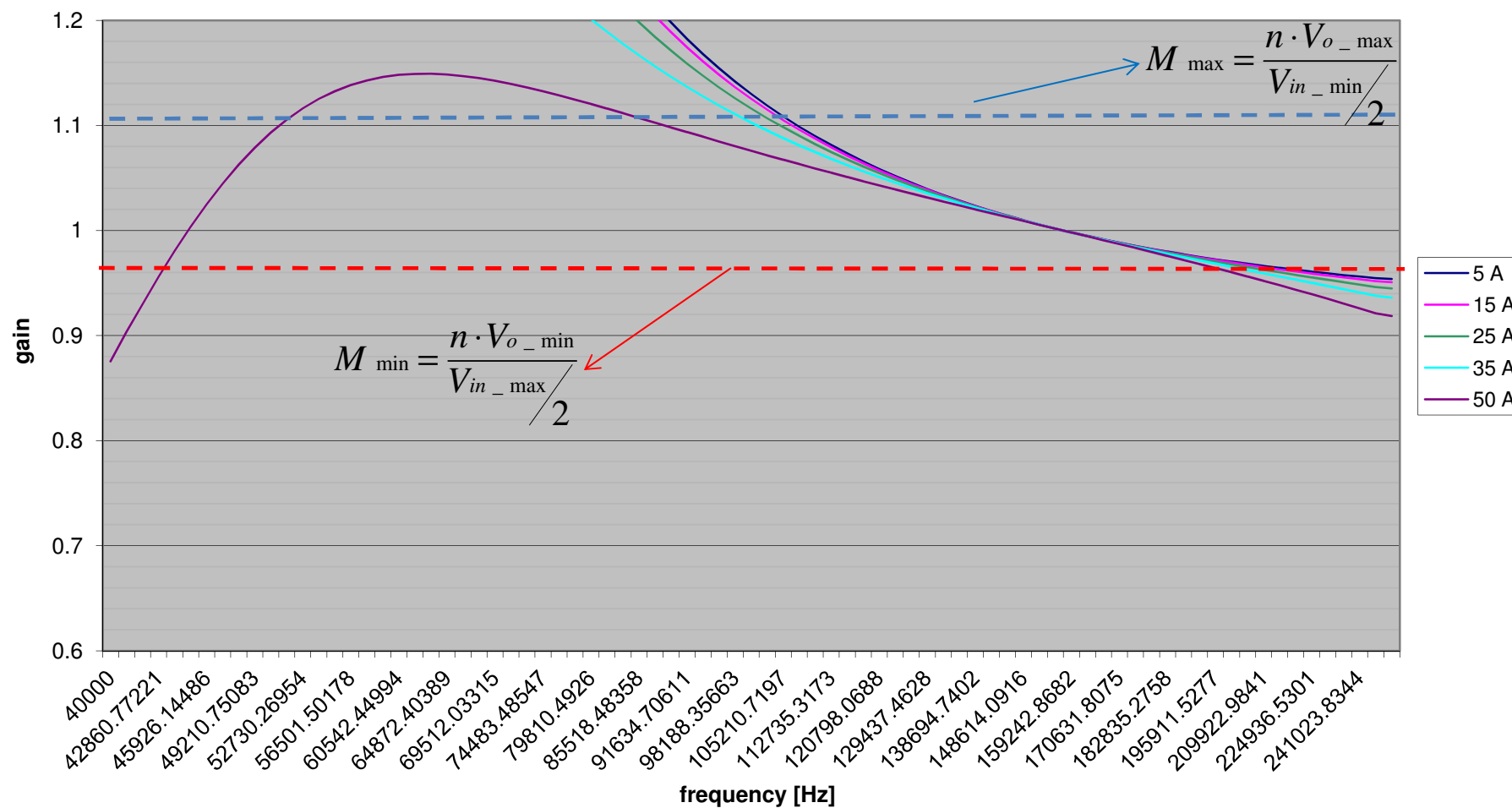


- $n = V_{in_nom} / (2 \times V_o) = 380 / (2 \times 12) \approx 16$
- $L_m = 195 \mu H$
- $L_r = 15.5 \mu H$
- $L_n = L_m / L_r = 12.5$
- $C_r = 66 nF$

$$f_o = \frac{1}{2\pi \cdot \sqrt{L_r \cdot C_r}} = 157 kHz$$

$$f_p = \frac{1}{2\pi \cdot \sqrt{(L_r + L_m) \cdot C_r}} = 42.7 kHz$$

dc-gain curve (600W LLC hardware revision E02)



Energy related calculations (ref. IPP60R190P6 device parameters)



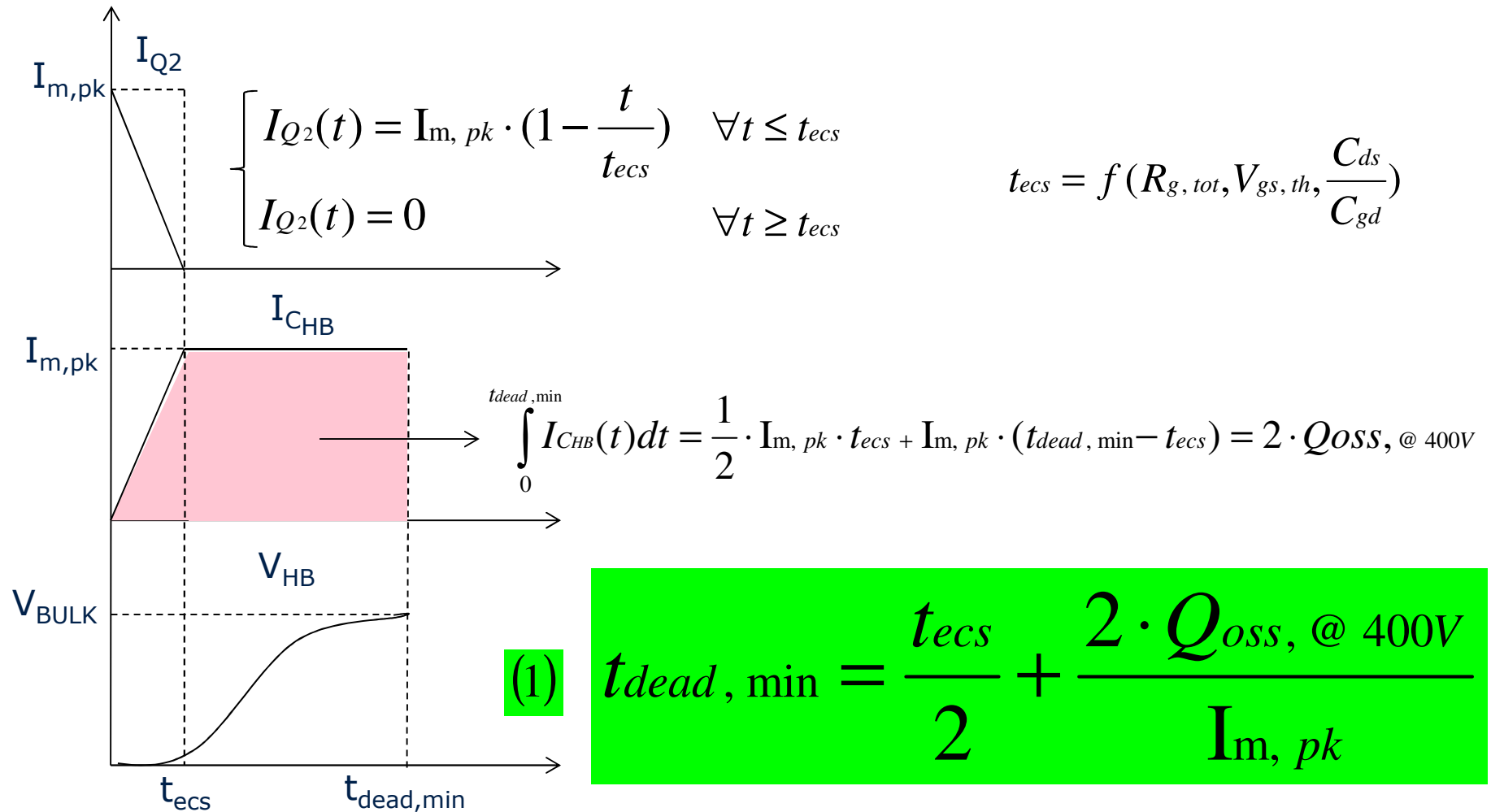
$$I_{mag_min} = \frac{2 \cdot \sqrt{2}}{\pi} \cdot \frac{n \cdot V_o}{2\pi \cdot f_{sw_max} \cdot L_m} = 0.672 A$$

$$E_{nres_min} = \frac{1}{2} \cdot (L_m + L_r) \cdot I_{mag_min}^2 = 95.1 \mu J$$

$$E_{ncap_max} = \frac{1}{2} \cdot (2Co(er)) \cdot V_{DS_max}^2 \approx 9 \mu J$$

$$\Rightarrow E_{nres_min} > E_{ncap_max}$$

$Q_{oss}, I_{mag,pk}, t_{dead,min}, t_{ecs}$ relationship



Time related calculations (ref. IPP60R190P6 device parameters)



$$I_{mag_min} = \frac{2 \cdot \sqrt{2}}{\pi} \cdot \frac{n \cdot V_o}{2\pi \cdot f_{sw_max} \cdot L_m} = 0.672A$$

$$I_{mag_max} = \frac{2 \cdot \sqrt{2}}{\pi} \cdot \frac{n \cdot V_o}{2\pi \cdot f_{sw_min} \cdot L_m} = 1.66A$$

$$t_{dead, min} = \frac{t_{ecs}}{2} + \frac{2 \cdot Q_{oss, @ 400V}}{I_{mag, max}} \approx 130n \text{ sec}$$

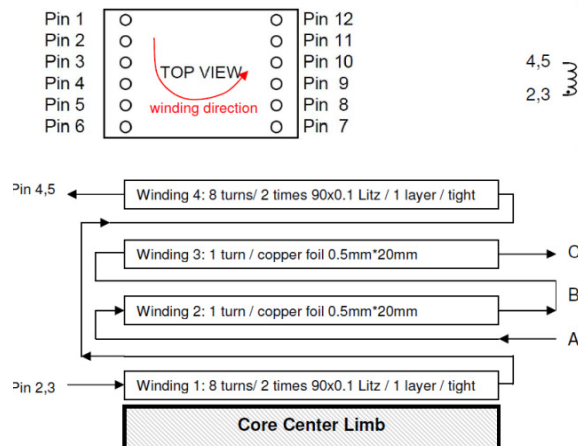
$$t_{dead, max} = \frac{t_{ecs}}{2} + \frac{2 \cdot Q_{oss, @ 400V}}{I_{mag, min}} \approx 311n \text{ sec}$$

Main transformer structure: PQ35/35 core with TDK PC95 ferrite material



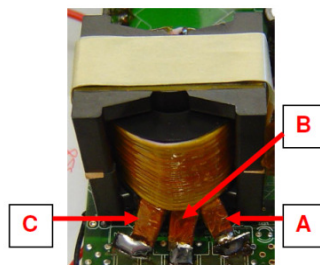
LLC main transformer

Core form and material	PQ35/35, PC95 (TDK)
Bobbin	Epcos, B65882E0012T001
Primary inductance L_p	195 μ H, measured between 2,3 and 4,5, other pins open
Leakage inductance L_k	1,5 μ H, measured between 2,3 and 4,5, other pins shorted
Isolation voltage V_{iso}	2500V _{rms} / 50Hz, 1min (between 2,3,4,5 and A,B,C)



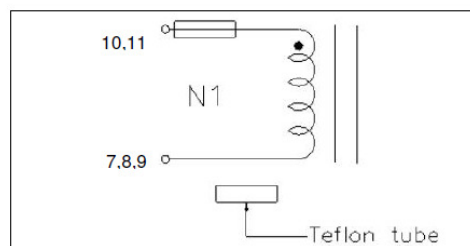
Windings	Start	End	Wire	Turns	Layers	Method
1	2,3	Float	2 times 90x0.1mm Litz	8	1	Tight
2	A	B	0.5mm*20mm copper foil	1	1	Tight
3	B	C	0.5mm*20mm copper foil	1	1	Tight
4	Float	4,5	2 times 90x0.1mm Litz	8	1	Tigh

Connection of secondary copper foil:



Technical Data Sheet		
Customer : Infineon Technologies	Part designation : SP-PQ 35/35	Customer part number :
		<p>Core / material / air gap PQ35/35 / K2008 or equiv. / 0,25</p> <p>Nominal inductance $LI+LVI = 195\mu H \pm 15\%$</p> <p>Ratio of transformation 8 : 1 : 1 : 8</p> <p>Dielectric strength (50Hz/1s) 2,5kV (prim - sec)</p> <p>Leakage inductance max. 3μH</p> <p>Operating temperature -25°C - +125°C</p> <p>Storage temperature -25°C - +85°C</p> <p>Humidity- / application class F (DIN 40040)</p>

Core form and material	RM12, N87 (Epcos)
Bobbin	Epcos, B65816C1512T001
Inductance	14µH



Windings	Start	End	Wire	Turns	Layers	Method
N1	7.8.9	10.11	120x0.1mm Litz	9	1	Tight

Customer : Infineon Technologies

Part designation : SP-RM 12

Customer part number :

Technical drawing of the SP-RM 12 component, showing dimensions and pin connections.

Dimensions:

- max. 46
- max. 41
- 25.4±0.3
- 33.02±0.3
- max. 25.5
- 4.5±0.5
- Ø1

Pin connections:

- 1, 6, 7, 12
- Al
- EI
- a.)
- WS links



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